Homework 1

1. (a) Find the quality (Q) factor of the cavity.

$$Q = \omega \tau = \frac{2\pi c}{\lambda_0} \tau$$

$$\tau = \frac{n}{\alpha c}$$

$$\alpha = \alpha_m + \alpha_i = \frac{1}{2L} \ln \frac{1}{R_1 R_2} + \alpha_i$$

Using $\alpha_i = 10 \text{ cm}^{-1}$, $R_1 = 1$, $R_2 = 0.99$, and $L = 1\mu\text{m}$, we find

$$\alpha_m = 50.25 \text{ cm}^{-1},$$

$$\alpha = 60.25 \text{ cm}^{-1}$$
.

Plugging in, and using $\lambda_0 = 1\mu m$ and n = 3.5, we find

$$Q = \frac{2\pi\cancel{e}}{\lambda_0} \frac{n}{\alpha\cancel{e}} = 3650.$$

(b) Find the threshold gain and quantum efficiency of the laser.

$$g_{th} = \frac{\alpha}{\Gamma} = 60.25 \text{ cm}^{-1}$$

using α from before and $\Gamma = 1$.

$$\eta = \frac{\alpha_m}{\alpha_i + \alpha_m} = 0.834$$

using α_m and α_i from before.

2. (a) What is the total Q of the cavity? Start with the definition of Q:

$$Q = \omega \frac{E}{P_{tot}} = \omega \frac{E}{P_r + P_m + P_s},$$

where P_{tot} is total power lost, and P_r , P_m , and P_s are power lost in radiation, metal, and semiconductor respectively. We also have

$$P_m = \omega \frac{0.3E}{Q_m},$$

$$P_r = \omega \frac{E}{Q_r},$$

$$P_s = 0,$$

where $Q_m = 50$ and $Q_r = 500$. Plugging these in and simplifying, we get

$$Q = \omega \frac{E}{0.3\omega E/Q_m + \omega E/Q_r}$$
$$= \frac{1}{0.3/Q_m + 1/Q_r}$$
$$= 125.$$

(b) What is the threshold gain and quantum efficiency of the laser?

$$g_{th} = \frac{\alpha}{\Gamma}$$

$$= \frac{2\pi n}{\lambda_0 Q \Gamma}$$

$$= 2154 \text{ cm}^{-1}.$$

using n=3, $\lambda_0=1\mu\mathrm{m}$, and $\Gamma=0.7$, since 70% of the energy is in the semiconductor, and only the semiconductor experiences gain.

$$\eta = \frac{P_r}{P_{tot}} = \frac{Q}{Q_r} = 0.25$$

3. (a) Use the energy reference below (i.e, $E_V=0$ and $E_C=E_g$, the bandgap energy), find E_1 and E_2 as functions of the photon energy, $\hbar\omega$.

$$E_{1} = -\frac{\hbar^{2}k^{2}}{2m_{h}^{*}}$$

$$E_{2} = E_{g} + \frac{\hbar^{2}k^{2}}{2m_{g}^{*}}$$

Subtract E_2 and E_1 and equate to $\hbar\omega$:

$$\begin{split} E_2 - E_1 &= \hbar \omega \\ &= E_g + \frac{\hbar^2 k^2}{2} \left(\frac{1}{m_e^*} + \frac{1}{m_h^*} \right) \\ &= E_g + \frac{\hbar^2 k^2}{2m_r^*} \end{split}$$

Rewriting E_1 and E_2 in terms of m_r^* and using the above equation, we get:

$$E_{1} = -\frac{\hbar^{2}k^{2}}{2m_{r}^{*}} \frac{m_{r}^{*}}{m_{h}^{*}}$$
$$= -\frac{m_{r}^{*}}{m_{h}^{*}} (\hbar\omega - E_{g})$$

$$E_2 = E_g + \frac{\hbar^2 k^2}{2m_r^*} \frac{m_r^*}{m_e^*}$$
$$= E_g + (\hbar\omega - E_g) \frac{m_r^*}{m_e^*}$$

(b) Derive $f_C(E_2(\hbar\omega))$ as a function of $\hbar\omega$.

$$f_C(E_2) = \frac{1}{1 + e^{(E_2 - F_C)/kT}}$$

$$= \frac{1}{1 + e^{\left(E_g + (\hbar\omega - E_g)\frac{m_T^*}{m_e^*} - F_C\right)/kT}},$$

plugging in for E_2 from above.

(c) Derive $f_V(E_1(\hbar\omega))$ as a function of $\hbar\omega$.

$$f_V(E_1) = \frac{1}{1 + e^{(E_1 - F_V)/kT}}$$

$$= \frac{1}{1 + e^{\left(-\frac{m_r^*}{m_h^*}(\hbar\omega - E_g) - F_V\right)/kT}}$$

(d) Calculate and plot the emission probability $f_e(\hbar\omega)=f_C(\hbar\omega)(1-f_V(\hbar\omega))$ for photon energies from 0.8 to 1.5 eV. Plot for two temperatures: T = 0 and T = 300 K.

Simply plug in f_C and f_V found above:

$$f_e(\hbar\omega) = \frac{1}{1 + e^{\left(E_g + (\hbar\omega - E_g)\frac{m_r^*}{m_e^*} - F_C\right)/kT}} \left(1 - \frac{1}{1 + e^{\left(-\frac{m_r^*}{m_h^*}(\hbar\omega - E_g) - F_V\right)/kT}}\right)$$

To use this equation we must find F_C and F_V .

Since $F_C - F_V > E_g$, F_C and/or F_V is degenerate. Since $m_e^* < m_h^*$, electrons are degenerate: $F_C > E_g$. Assume holes are also degenerate: $F_V < 0$. Then we have

$$n \propto N_C (F_C - E_g)^{3/2} \propto m_e^{*3/2} (F_C - E_g)^{3/2}$$

 $p \propto N_V (-F_V)^{3/2} \propto m_h^{*3/2} (-F_V)^{3/2}$

with the same proportionality factor for n and p. Since n = p, we have

$$\frac{m_h^*}{m_e^*} = \frac{F_C - E_g}{-F_V}$$

$$4 = \frac{F_V + 1.2eV - 1eV}{-F_V}$$

$$-4F_V = F_V + 0.2eV$$

$$F_V = -0.04eV$$

$$F_C = F_V + 1.2eV = 1.16eV.$$

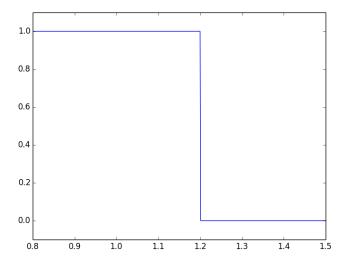


Figure 1: f_e vs $\hbar\omega$ (eV) at T=0K.

Note that $F_V < 0$, justifying our original assumption. f_e is plotted in Figs. 1 and 2.

(e) Repeat part d) for the Fermi inversion factor $f_g(\hbar\omega) = f_C(\hbar\omega) - f_V(\hbar\omega)$.

$$f_g(\hbar\omega) = \frac{1}{1 + e^{\left(E_g + (\hbar\omega - E_g)\frac{m_r^*}{m_e^*} - F_C\right)/kT}} - \frac{1}{1 + e^{\left(-\frac{m_r^*}{m_h^*}(\hbar\omega - E_g) - F_V\right)/kT}}$$

 f_g is plotted in Figs. 3 and 4.

(f) Plot the gain spectra for T=0 and T=300 K for the condition given in d).

$$g(\hbar\omega) = C_0 |\hat{\mathbf{e}} \cdot \mathbf{p}|^2 \rho_r (\hbar\omega - E_g) f_g(\hbar\omega)$$

$$C_0 = \frac{\pi e^2}{nc\epsilon_0 m_0^2 \omega}$$

$$|\hat{\mathbf{e}} \cdot \mathbf{p}|^2 = \frac{m_0}{6} E_p, \quad E_p = 25.7eV$$

$$\rho_r (\hbar\omega - E_g) = H(\hbar\omega - E_g) \frac{1}{2\pi^2} \left(\frac{2m_r^*}{\hbar^2}\right)^{3/2} \sqrt{\hbar\omega - E_g}$$

$$f_g(\hbar\omega) = f_C(\hbar\omega) - f_V(\hbar\omega)$$

Assuming n = 3.5, $g(\hbar\omega)$ is plotted in Figs. 5 and 6.

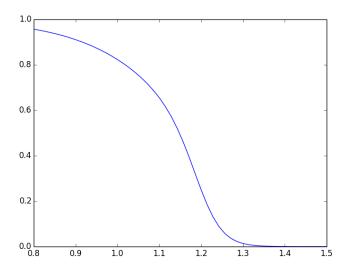


Figure 2: f_e vs $\hbar\omega$ (eV) at T=300K.

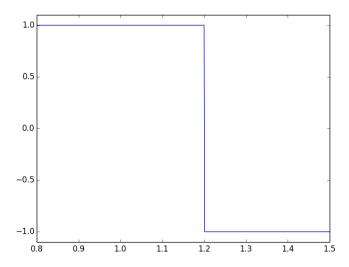


Figure 3: f_g vs $\hbar\omega$ (eV) at T=0K.

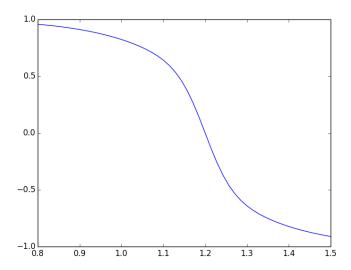


Figure 4: f_g vs $\hbar\omega$ (eV) at T=300K.

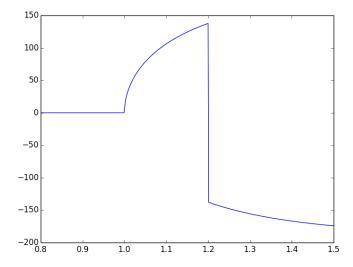


Figure 5: $g \text{ (cm}^{-1}) \text{ vs } \hbar \omega \text{ (eV) at } T = 0K.$

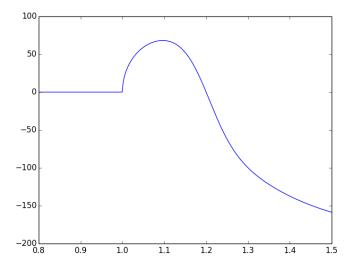


Figure 6: $g \text{ (cm}^{-1}) \text{ vs } \hbar\omega \text{ (eV) at } T = 300K.$

(g) Plot the spontaneous emission spectra for T=0 and T=300~K for the condition given in d).

$$r_{\rm spon}(\hbar\omega) = \frac{8\pi n^2 (\hbar\omega)^2}{h^3 c^2} \frac{f_e(\hbar\omega)}{f_g(\hbar\omega)} g(\hbar\omega)$$

 $r_{\rm spon}$ is plotted in Figs. 7 and 8.

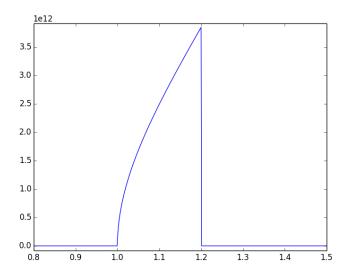


Figure 7: $r_{\rm spon}~({\rm eV}^{-1}{\rm um}^{-3}{\rm s}^{-1})$ vs $\hbar\omega~({\rm eV})$ at T=0K.

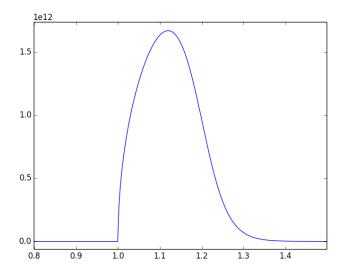


Figure 8: $r_{\rm spon}~({\rm eV}^{-1}{\rm um}^{-3}{\rm s}^{-1})$ vs $\hbar\omega~({\rm eV})$ at T=300K.